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13. ABSTRACT (Maximum 200 words)				
This program funded the purchase of a Sun Ultra 60 dual processor workstation and tunable laser modules from New Focus that				
complement our existing tunable diode laser and extend the tuning range from 1470 nm to 1620 nm. These were, and continue to be, used in our work on photonic crystal devices. In particular, the workstation has been used to calculate modes for the design of a single				
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Final Report for Research Instrumentation for Photonic Bandgap Photonics

4. Statement of the Problem Studied

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Final Report for Research Instrumentation for Photonic Bandgap Photonics

5. Summary

This proposal was for a tunable laser and a workstation. These are important components in the work on two-dimensional photonic bandgap devices going on in my research group. The original proposal was intended for these two pieces of equipment to be used for photonic crystal waveguides and microcavity lasers. They have been used for these projects. In addition, since the time of the proposal, the work on photonic crystals in my group has broadened. We are also currently working on engineering the radiation pattern of these microcavity lasers and using the super-dispersion of photonic crystals to guide optical beams. In this report, I'll discuss the progress by research project. I'll start with the work on microcavities lasers.

We have demonstrated, in collaboration with Professors Scherer and Yariv at Caltech and Professor Dapkus here at USC a microcavity based on a single defect in a two-dimensional photonic crystal. The structure is shown in figure 1. The cavity

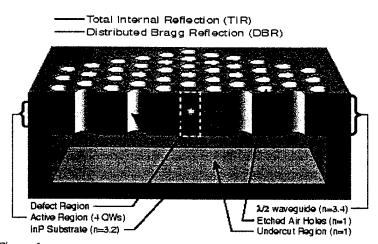
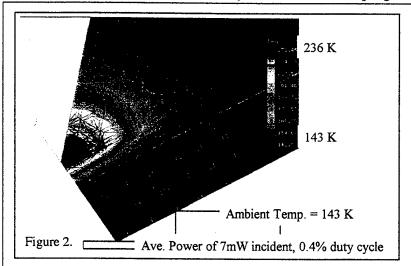


Figure 1.

consists of a 220 nm thick semiconductor membrane that contains 4 InGaAsP quantum wells. membrane is formed by removing an underlying InP layer selectively using HC1. Before semiconductor membrane formed, twodimensional photonic crystal is defined into it using an electron-beam lithography step, followed

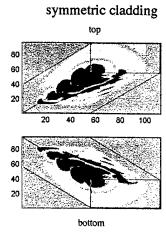
by an ion beam mill, a reactive ion etch, and a chemically-assisted ion beam etch. This work has resulted in three publications to date [1-3]. The initial demonstration was done in pulsed operation at low temperature [1]. Subsequent work has led to roomtemperature pulsed operation [2], and a demonstration of lithographically defined lasing wavelengths [3]. This last work demonstrated tuning from 1500 to 1625 nm from a single wafer by lithographically varying the lattice constant and the ratio of the hole Professor Dapkus and I are currently pursuing radius to the lattice constant. microcavities that will operate continuously at room temperature. The problem with the initial cavity is that it does not dissipate heat effectively. Shown below in figure 2 is a calculation of the temperature distribution in the photonic crystal microcavity. The figure shows one-sixth of the cavity. This calculation was done in my group using commercial software. Here the substrate is held at the temperature of the initial demonstration, 143 K. The membrane is heated by absorbing optical power and is about 100 degrees hotter than the substrate. In this calculation, the membrane is allowed to cool through conduction, convection, and radiation. This elevated temperature of the

membrane reduces the peak gain and makes it difficult to achieve continuous lasing. Therefore, we are working on an alternative structure. The new structure will be fusion bonded to a sapphire layer, which may eventually itself be bonded to a backside emitting VCSEL array for optical pumping. The sapphire will provide a thermally conductive substrate to conduct the heat as well as a reasonably low-index material for mode confinement. This work is funded by a DARPA STAB program. The sapphire, however,

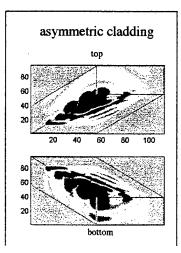


complicates electromagnetic design of the cavity. Most importantly, the symmetry broken so that there longer no exist purely even and odd modes. This rigorously eliminates the bandgap of the photonic crystal. Practically, the bandgap still exists

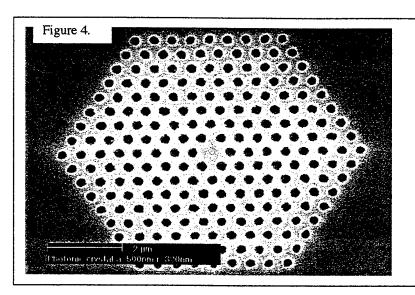
if the waveguide is made thick enough. In this case, the semiconductor waveguide cladding is symmetric on each side of the quantum wells and thick enough so that the asymmetry is a small perturbation on the cavity mode. Shown below in figure 3 is a finite-difference time-domain calculation of the fields in a photonic bandgap cavity. The figure on the left has symmetric air cladding on the top and bottom. On the right, the top cladding is air and the bottom cladding is sapphire. This code was written by my students, and runs on the dual-processor Sun Ultra 60 workstation purchased under this program. As can be seen in the figure, the cavity on the right radiates preferentially into the high-index substrate. The calculated quality factor of the cavity with the asymmetric cladding can be made as large or larger than the symmetric air-cladded structure if the semiconductor is made thick enough.





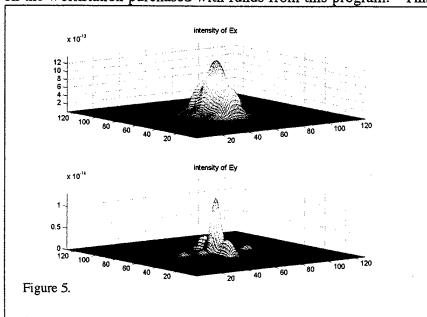


Practically, the Q is limited by the obtainable etch depth. This will determine the maximum membrane thickness, and the vertical loss decreases with increasing semiconductor thickness.



These microcavities are currently being fabricated here at USC. Shown below in figure 4 is an electron micrograph of an undercut membrane fabricated in my group. We are also collaborating with Professor Dapkus to fabricate photonic crystal microcavities with a farfield radiation pattern that has been engineered produce either to linearly polarized circular

beam, or to produce a fan-out pattern for free-space interconnections between electronics layers. This work is being supported by a DARPA STAB program and a DARPA WASSP program, respectively. In order to perform this engineering of the radiation field, we must be able to model this field. Shown below is a calculated radiation field for the microcavity laser demonstrated in [1-3]. This calculation was done in my group on the workstation purchased with funds from this program. This calculation was done

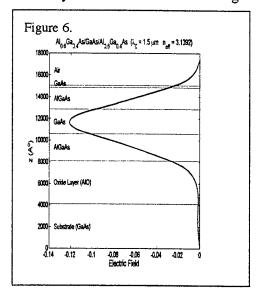


by calculating the complex near-field the finitedifference timedomain method. This field was then the input for a vector-diffraction theory calculation of the far-field. The figure illustrates that the x-component of the electric field is an order of magnitude larger that the ycomponent of the electric radiation

field. This is in agreement with data taken at Caltech on the photonic crystal defect lasers.

The finite-difference time-domain calculations were written in C. These calculations can be very time-consuming so we have augmented the workstation purchased under this program with more workstations. The goal here is to use the multiple workstations to do these calculations in parallel. We are currently debugging this parallel version of the code.

We are also designing and fabricating photonic bandgap defined waveguides. Here, the waveguides are defined in a GaAs/AlGaAs slab-waveguide epitaxial structure. The layer structure is shown in figure 6. Below the bottom waveguide cladding is a layer



of AlAs that will be converted to Al, O, by wetoxidation. The purpose of this layer is to isolate the guided mode from the high-index substrate. Or, in other words, the AlO is included to guarantee that the waveguide mode is not a leaky Here again we can do finite-difference time-domain calculations to model the waveguide. We are also considering other approaches to waveguide modeling. These other approaches include calculating both the reflectivity and the phase of the reflection coefficient. This works is based on the work of Sakoda in [4-5]. Once we have the complex reflection coefficient, we can construct the waveguide mode using a transverseresonance scheme. An example of a field calculated using this method is shown below in

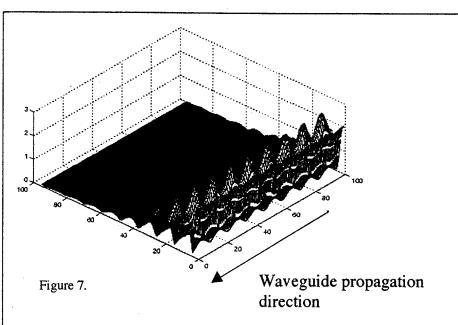
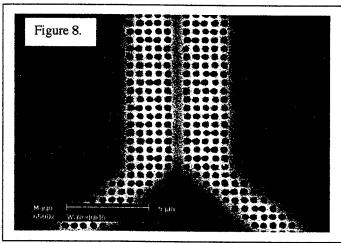


figure 7. In the figure, half of the field is shown. The other half is identical because of the symmetry. The drawback of this method is that it is a purely twodimensional calculation. This method, then, is incapable of dealing with the critical

issue of guided versus leaky mode behavior of these waveguides. We are also working

on a finite-element code to calculate the eigenmodes of these structures directly. This has the advantage of eliminating the filtering routines that accompany solving for an eigenmode using the finite-difference time-domain algorithms. These calculations are also being done on the workstation purchased using funds from this program. Our goal is to do three-dimensional calculations of the photonic crystal waveguides.

We are also fabricating two-dimensional photonic crystal waveguides here at USC. This is done in collaboration with, and with support from, Agilent. Here the

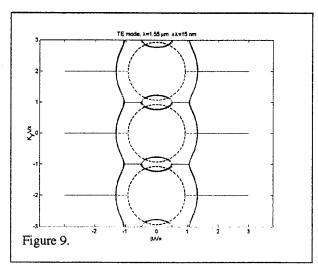


pattern transfer is very similar to that of the photonic crystal microcavities. The etching here at USC involves an Ar+ ion beam mill, a reactive ion etch, and an electron cyclotron resonance system etch. In the ECR, the GaAs structures are etched with а BCl₂/Ar mixture, and the InP structures are etched with a CH₄/H₂/Ar recipe. micrograph shows the inputcoupling region. This is one

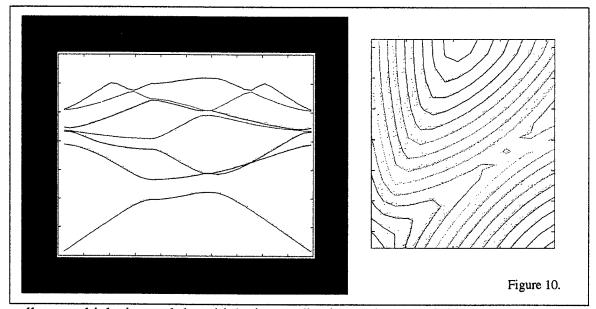
of the programs for which the New Focus tunable laser was purchased. The laser complements an existing waveguide characterization setup in Professor Dapkus' lab. This setup is shared by the two research groups. The laser modules are controlled by an existing laser controller. Experimentally, we are interested in measuring the waveguide loss and in understanding the frequency range over which a guided mode exists.

Finally, we are also working on designing, fabricating, and characterizing structures that utilize the eigenstates of the periodic lattice for their functionality. In particular, we are working on the super-dispersion effects reported by NEC [6-7]. Here there is a program in collaboration with Professor Levi at USC funded by a DARPA STAB program. In these devices, the optical behavior is "built-in". The bandedge states are both spatially and spectrally dispersive. We are investigating both one-dimensional

two-dimensional and periodic structures. In one-dimension, the analysis can be can be done nearly analytically. The eigenstates of the one-dimensionally periodic media can be solved using a matrix method [8]. Then to solve for the guided modes of the slab, we follow Russell, [9-10], and expand the periodic part of the Bloch functions in terms of spatial harmonics and keep only the first two terms. These are then matched to fields in the air cladding regions. Shown at right is the dispersion

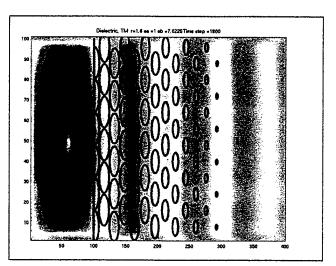


surface of the one-dimensional media. This curve is the dispersion surface for an infinite one-dimensional media. Near the Brillouin zone edge, there is a region where the desired dispersion occurs. This phenomenon has been understood for many years. See, for example, [11]. We are also interested in investigating this effect in two-dimensional structures. In two-dimensions, the dispersive region does not have to occur at the zone boundary. This gives increased freedom in designing the coupling angles. For these devices, the bandstructure is calculated using either a finite-difference time-domain procedure or a plane-wave basis bandstructure calculation. The finite-difference timedomain method starts with a field with a given k. This field is allowed to propagate before Fourier transforming the field to obtain the eigenfrequencies of the propagating modes. To obtain the bandstructure, the initial k is varied across the Brillouin zone. The figure shows a plane wave bandstructure calculation and constant frequency contours over a quarter of the Brillouin zone for a particular band. Since the group velocity is normal to the constant frequency contours in the direction of increasing frequency, it is clear that there are regions in this plot where the propagation direction is changing with frequency. We are planning to investigate the use of these structures for beamsteering as



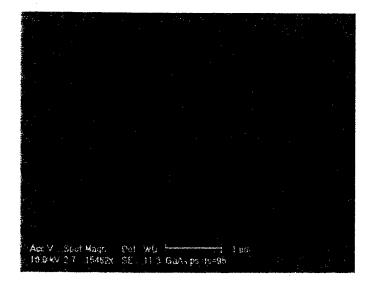
well a s multiplexing and demultiplexing applications. As part of this investigation we are also interested in understanding how robust these structures are compared to device geometries that contain a defect guiding region. We are also very interested in understanding how to efficiently couple fields from non-photonic crystal media into photonic crystal media. As an example, the figure below shows a point source in free space radiating into a region in which the photonic crystal lattice constant is changing. Here we see a factor of 6 reduction in the reflectivity compared to a semiconductor interface, but this number has not been corrected for the reduced effective index in the periodically varying photonic crystal case.

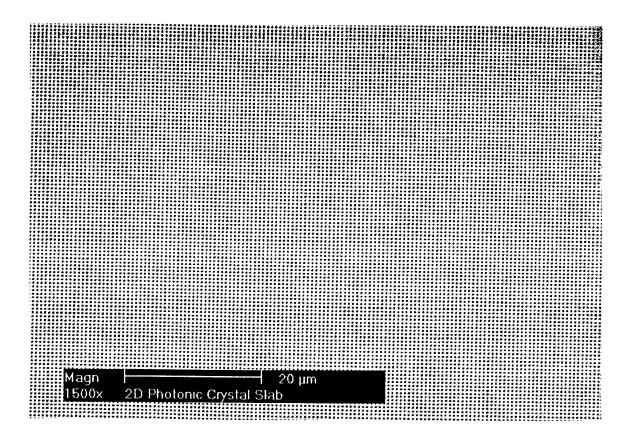
Again, all of these calculations are being done with code written by my students on workstations in the lab. Finally, we are also beginning to fabricate these one-dimensional and two-dimensional periodic structures. Examples are shown in micrographs below. In the onedimensional case, the lines are 80 nm wide. Below that, is a twodimensional lattice. The lithography is done on an SEM converted by my students to do lithography. maximum pattern size is determined



by the magnification of the microscope at which the pattern is written

Figure 12.





- 7. List of all participating scientific personnel No graduate students were funded by this DURIP program, but the following graduate students have used the equipment purchased: Roshanak Shafiiha, Cheolwoo Kim, Woo Jun Kim, Andrew Stapleton, Po-Tsung Lee.
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